

PRODUCT RELIABILITY REPORT  
FOR

**DS14285, Rev A3**

**Dallas Semiconductor**

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**Conclusion:**

The following qualification successfully meets the quality and reliability standards required of all Dallas Semiconductor products:

DS14285, Rev A3

In addition, Dallas Semiconductor's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at <http://www.maxim-ic.com/TechSupport/dsreliability.html>.

**Device Description:**

A description of this device can be found in the product data sheet. You can find the product data sheet at [http://dbserv.maxim-ic.com/l\\_datasheet3.cfm](http://dbserv.maxim-ic.com/l_datasheet3.cfm).

**Reliability Derating:**

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

$$AfT = \exp((Ea/k) * (1/Tu - 1/Ts)) = tu/ts$$

AfT = Acceleration factor due to Temperature  
tu = Time at use temperature (e.g. 55°C)  
ts = Time at stress temperature (e.g. 125°C)  
k = Boltzmann's Constant (8.617 x 10<sup>-5</sup> eV/°K)  
Tu = Temperature at Use (°K)  
Ts = Temperature at Stress (°K)  
Ea = Activation Energy (e.g. 0.7 eV)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7eV will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

$$AfV = \exp(B * (Vs - Vu))$$

AfV = Acceleration factor due to Voltage  
Vs = Stress Voltage (e.g. 7.0 volts)  
Vu = Maximum Operating Voltage (e.g. 5.5 volts)  
B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

$$Fr = X / (ts * AfV * AfT * N * 2)$$

X = Chi-Sq statistical upper limit  
N = Life test sample size

Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

$$MTTF = 1/Fr$$

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

**FAILURE RATE:**                      **MTTF (YRS): 84930**                      **FITS: 1.3**

The parameters used to calculate this failure rate are as follows:

**Cf: 60%**                      **Ea: 0.7**                      **B: 0**                      **Tu: 25 °C**                      **Vu: 5.5 Volts**

The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data.

**Device Information:**

Process: 1P, 1M, 1.2um, Ndepletion, TEOS SP, WJ BPSG,  
 Passivation: Passivation w/Nov TEOS Oxide-Nitride  
 Die Size: 125 x 197  
 Number of Transistors: 0  
 Interconnect: Aluminum / 1% Silicon / 0.5% Copper  
 Gate Oxide Thickness: 225 Å

**OPERATING LIFE**

DESCRIPTION	DATE	CODE	CONDITION	READPOINT	QTY	FAILS	FA#
HIGH VOLTAGE LIFE	9904		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9906		125C, 7.0 VOLTS	1000 HRS	115	0	
HIGH VOLTAGE LIFE	9907		125C, 7.0 VOLTS	1000 HRS	116	1	BATT LEAK
HIGH VOLTAGE LIFE	9908		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9910		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9913		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9917		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9929		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	9929		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	0007		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	0017		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	0019		125C, 7.0 VOLTS	1000 HRS	116	0	
HIGH VOLTAGE LIFE	0020		125C, 7.0 VOLTS	1000 HRS	116	0	
INFANT LIFE	0033		125C, 7.0 VOLTS	48 HRS	234	0	
HIGH VOLTAGE LIFE	0033		125C, 7.0 VOLTS	1000 HRS	77	0	
						<b>Total:</b>	<b>1</b>

**FAILURE RATE:**                      **MTTF (YRS): 84930**                      **FITS: 1.3**